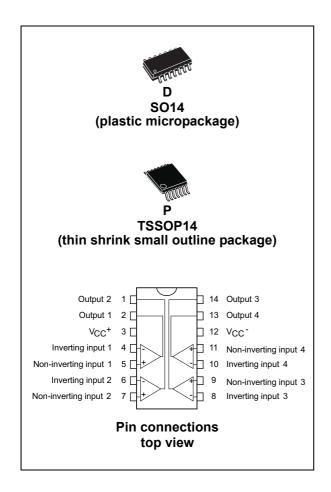


Micropower quad CMOS voltage comparator

Datasheet - production data



Features

- Extremely low supply current:
 9 μA typ./comparator
- Wide single supply range 2.7 V to 16 V or dual supplies (±1.35 V to ±8 V)
- Extremely low input bias current: 1 pA typ.
- Extremely low input offset current: 1 pA typ.
- Input common-mode voltage range includes GND
- High input impedance: 10¹² Ω typ.
- Fast response time: 1.5 μs typ. for 5 mV overdrive
- Pin-to-pin and functionally compatible with bipolar LM339 device

Description

The TS339 device is a micro-power, CMOS, quad voltage comparator with extremely low consumption of 9 μ A typ./comparator (20 times less than the bipolar LM339). Similar performances are offered by the quad micro-power comparator TS3704 with a push-pull CMOS output. Thus response times remain similar to the LM339 device.

Table 1. Device summary

Order code	Temperature range Package Packaging		Marking		
TS339CD/CDT	0 °C, 70 °C	SO14	Tube or tape and reel	S339C	
TS339IDT	-40 °C, 125 °C	3014	Tube of tape and feel	S339I	
TS339IPT	-40 C, 125 C	TSSOP14	Tape and reel	33391	

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1 Absolute maximum ratings

Table 2. Key parameters and their absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CC} ⁺	Supply voltage ⁽¹⁾	18	
V _{id}	Differential input voltage ⁽²⁾	±18	V
V _i	Input voltage ⁽³⁾	18	V
V _o	Output voltage	18	
Io	Output current	20	mA
I _F	Forward current in ESD protection diodes on inputs ⁽⁴⁾	50	ША
p _d	Power dissipation ⁽⁵⁾ SO14 TSSOP14	830 710	mW
T _{stg}	Storage temperature range	-65 to +150	°C
	HBM: human body model ⁽⁶⁾	50	
ESD	MM: machine model ⁽⁷⁾	40	V
	CDM: charged device model	800	

- 1. All voltage values, except the differential voltage, are with respect to network ground terminal.
- 2. Differential voltages are the non-inverting input terminal with respect to the inverting input terminal.
- Excursions of input voltages may exceed the power supply level. As long as the common mode voltage [V_{icm}=(V_{in}+ V_{in}-)/2] remains within the specified range, the comparator will provide a stable output state. However, the maximum current through the ESD diodes (IF) of the input stage must strictly be observed.
- 4. Guaranteed by design.
- 5. Pd is calculated with T $_{\rm amb}$ = +25 °C, T $_{\rm j}$ = +150 °C and R $_{\rm thja}$ = 150 °C/W for SO14 package R $_{\rm thja}$ = 175 °C/W for TSSOP14 package.
- 6. Human body model, 100pF discharged through a 1.5 $k\Omega$ resistor into pin of device.
- 7. Machine model ESD, a 200 pF cap is charged to the specified voltage, then discharged directly into the IC with no external series resistor (internal resistor $< 5 \Omega$), into pin to pin of device.



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2 Typical application schematics

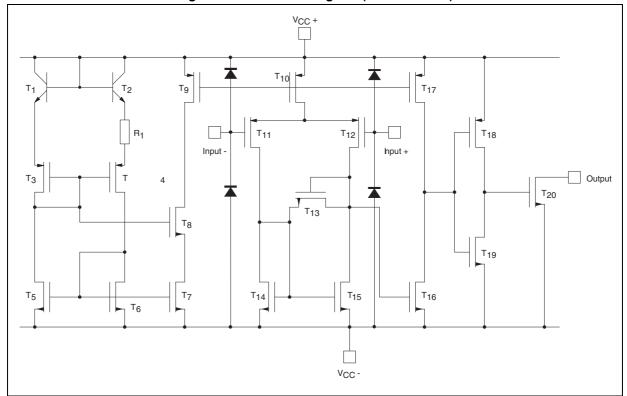


Figure 1. Schematic diagram (for 1/4 TS339)

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3 Electrical characteristics

Table 3. V_{CC}^+ = 3 V, V_{CC}^- = 0 V, T_{amb} = 25 °C (unless otherwise specified)

Symbol	Parameter	Min.	Тур.	Max.	Unit
V _{io}	Input offset voltage ⁽¹⁾ $V_{ic} = 1.5 \text{ V}$ $T_{min.} \le T_{amb} \le T_{max.}$			5 6.5	mV
l _{io}	Input offset current ⁽²⁾ $V_{ic} = 1.5 \text{ V}$ $T_{min.} \le T_{amb} \le T_{max.}$		1	300	рA
l _{ib}	Input bias current $^{(2)}$ V_{ic} = 1.5 V T_{min} . $\leq T_{amb} \leq T_{max}$.		1	600	PΛ
V _{icm}	Input common mode voltage range $T_{min}. \le T_{amb} \le T_{max}$	0		V _{CC} ⁺ -1.2 V _{CC} ⁺ -1.5	٧
CMR	Common-mode rejection ratio $V_{ic} = V_{icm \ min.}$		70		dB
SVR	Supply voltage rejection ratio $V_{CC}^+ = 3 \text{ V to 5 V}$		70		uБ
I _{OH}	High level output current $V_{id} = +1 \text{ V}, V_{OH} = 3 \text{ V}$ $T_{min.} \le T_{amb} \le T_{max.}$		2	40 1000	nA
V _{OL}	Low level output voltage V_{id} = -1 V, I_{OL} = +6 mA T_{min} . $\leq T_{amb} \leq T_{max}$.		400	550 800	mV
Icc	Supply current (each comparator) No load - outputs low $T_{min.} \le T_{amb} \le T_{max.}$		9	20 25	μΑ
t _{PLH}	Response time low to high V_{ic} = 0 V, f = 10 kHz, T_{min} . $\leq T_{amb} \leq T_{max}C_L$ = 50 pF, overdrive = 5 mV TTL input		1.5 0.7		16
t _{PHL}	Response time high to low V_{ic} = 0 V, f = 10 kHz, R_L = 5.1 k Ω , C_L = 50 pF, overdrive = 5 mV TTL input		2.5 0.08		μs

^{1.} The specified offset voltage is the maximum value required to drive the output up to $2.5\ V$ or down to $0.3\ V$.

^{2.} Maximum values including unavoidable inaccuracies of the industrial test.

Electrical characteristics TS339

Table 4. V_{CC}^+ = 5 V, V_{CC}^- = 0 V, T_{amb} = 25 °C (unless otherwise specified)

Symbol	Parameter Parameter	Min.	Тур.	Max.	Unit
V _{io}	Input offset voltage ⁽¹⁾ $V_{ic} = 2.5 \text{ V}, V_{cc}^{+} = 5 \text{ V} \text{ to } 10 \text{ V}$ $T_{min.} \le T_{amb} \le T_{max.}$		1.4	5 6.5	mV
l _{io}	Input offset current ⁽²⁾ $V_{ic} = 2.5 \text{ V}$ $T_{min.} \le T_{amb} \le T_{max.}$		1	300	pA
l _{ib}	Input bias current ⁽²⁾ $V_{ic} = 2.5 \text{ V}$ $T_{min.} \le T_{amb} \le T_{max.}$		1	600	рΑ
V _{icm}	Input common mode voltage range $T_{min.} \leq T_{amb} \leq T_{max}$	0 0		V _{CC} ⁺ -1.2 V _{CC} ⁺ -1.5	V
CMR	Common-mode rejection ratio V _{ic} = 0 V		75		dB
SVR	Supply voltage rejection ratio $V_{CC}^+ = +5 \text{ V to } +10 \text{ V}$		85		ם
I _{OH}	High level output voltage V_{id} = 1 V, V_{OH} = +5 V T_{min} . $\leq T_{amb} \leq T_{max}$.		27	40 1000	nA
V _{OL}	Low level output voltage V_{id} = -1 V, I_{OL} = 6 mA T_{min} . $\leq T_{amb} \leq T_{max}$.		260	400 650	mV
Icc	Supply current (each comparator) No load - outputs low $T_{min} \le T_{amb} \le T_{max}$.		10	20 25	μА
t _{PLH}	Response time low to high V_{ic} = 0 V, f = 10 kHz, R_L = 5.1 k Ω C_L = 15 pF, overdrive = 5 mV Overdrive = 10 mV Overdrive = 20 mV Overdrive = 40 mV TTL input		1.5 1.2 1.1 0.9 0.8		μs
t _{PHL}	Response time high to low $V_{ic} = 0 \text{ V, } f = 10 \text{ kHz, } R_L = 5.1 \text{ k}\Omega \text{ C}_L = 15 \text{ pF, overdrive} = 5 \text{ mV}$ Overdrive = 10 mV Overdrive = 20 mV Overdrive = 40 mV TTL input		2.5 1.9 1.2 0.8 0.08		μο
t _f	Fall time f = 10 kHz, C_L = 50 pF, R_L = 5.1 k Ω overdrive 50 mV		30		ns

^{1.} The specified offset voltage is the maximum value required to drive the output up to $4.5\ V$ or down to $0.3\ V$.

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^{2.} Maximum values including unavoidable inaccuracies of the industrial test.

TS339 Package information

4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.



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Package information TS339

4.1 SO14 package information

B and a and

Figure 2. SO14 package outline

Table 5. SO14 package mechanical data

	Dimensions						
Symbol	mm			inch			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α			1.75			0.068	
a1	0.1		0.2	0.003		0.007	
a2			1.65			0.064	
b	0.35		0.46	0.013		0.018	
b1	0.19		0.25	0.007		0.010	
С		0.5			0.019		
c1			45° (t	yp.)			
D	8.55		8.75	0.336		0.344	
E	5.8		6.2	0.228		0.244	
е		1.27			0.050		
e3		7.62			0.300		
F	3.8		4.0	0.149		0.157	
G	4.6		5.3	0.181		0.208	
L	0.5		1.27	0.019		0.050	
М			0.68			0.026	
S	8° (max.)						

TS339 Package information

4.2 TSSOP14 package information

Figure 3. TSSOP14 package outline

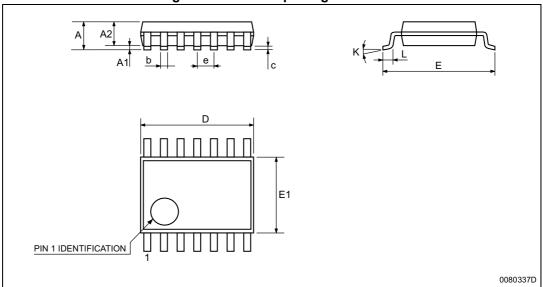


Table 6. TSSOP14 package mechanical data

	Dimensions							
Symbol		mm.		inch				
	Min.	Тур.	Max.	Min.	Тур.	Max.		
Α			1.2			0.047		
A1	0.05		0.15	0.002	0.004	0.006		
A2	0.8	1	1.05	0.031	0.039	0.041		
b	0.19		0.30	0.007		0.012		
С	0.09		0.20	0.004		0.0089		
D	4.9	5	5.1	0.193	0.197	0.201		
E	6.2	6.4	6.6	0.244	0.252	0.260		
E1	4.3	4.4	4.48	0.169	0.173	0.176		
е		0.65 BSC			0.0256 BSC			
K	0°		8°	0°		8°		
L	0.45	0.60	0.75	0.018	0.024	0.030		

Revision history TS339

5 Revision history

Table 7. Document revision history

Date	Revision	Changes		
Jan. 2003	1	Initial release.		
Aug. 2005 2		- PPAP references inserted in the datasheet see <i>Table 1: Order</i> odes on page 1 ESD protection inserted in <i>Table 2 Key parameters and their</i> bsolute maximum ratings on page 2.		
04-Sep-2012	3	Updated Features, Table 1, removed TS339IYD and TS339IYDT from Table 1. Updated ECOPACK text, reformatted Section 4: Package information. Minor corrections throughout document.		
21-Feb-2014 4		Removed DIP package Features: updated fast response time Device summary: removed order codes TS339CN, TS339IN, and TS339ID; added temperature range for order codes TS339IDT and TS339IPT		



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